

# 2SC5452

# Ultrahigh-Definition CRT Display Horizontal Deflection Output Applications

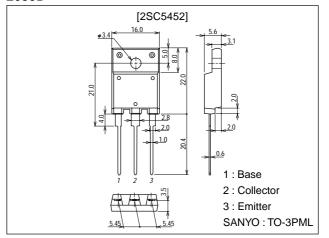
#### **Features**

- · High speed.
- · High breakdown voltage (V<sub>CBO</sub>=1600V).
- · High reliability (Adoption of HVP process).
- · Adoption of MBIT process.

## **Package Dimensions**

unit:mm

2039D



# **Specifications**

#### **Absolute Maximum Ratings** at Ta = 25°C

| Parameter                    | Symbol           | Conditions | Ratings     | Unit |
|------------------------------|------------------|------------|-------------|------|
| Collector-to-Base Voltage    | V <sub>CBO</sub> |            | 1600        | V    |
| Collector-to-Emitter Voltage | VCEO             |            | 800         | V    |
| Emitter-to-Base Voltage      | V <sub>EBO</sub> |            | 6           | V    |
| Collector Current            | IC               |            | 20          | Α    |
| Collector Current (Pulse)    | I <sub>CP</sub>  |            | 40          | Α    |
| Collector Dissipation        | PC               |            | 3           | W    |
|                              |                  | Tc=25°C    | 75          | W    |
| Junction Temperature         | Tj               |            | 150         | °C   |
| Storage Temperature          | Tstg             |            | -55 to +150 | °C   |

#### **Electrical Characteristics** at Ta = 25°C

| Parameter                            | Symbol                | Conditions                                 | Ratings |     |     | Unit   |
|--------------------------------------|-----------------------|--|---------|-----|-----|--------|
|                                      | Symbol                |  | min     | typ | max | Office |
| Collector Cutoff Current             | ICES                  | V <sub>CE</sub> =1600V, R <sub>BE</sub> =0 |         |     | 1.0 | mA     |
| Collector-to-Emitter Sustain Voltage | V <sub>CEO(sus)</sub> | I <sub>C</sub> =100mA, I <sub>B</sub> =0   | 800     |     |     | V      |
| Emitter Cutoff Current               | I <sub>EBO</sub>      | V <sub>EB</sub> =4V, I <sub>C</sub> =0     |         |     | 1.0 | mA     |
| Collector Cutoff Current             | ICBO                  | V <sub>CB</sub> =800V, I <sub>E</sub> =0   |         |     | 10  | μA     |
| DC Current Gain                      | h <sub>FE</sub> 1     | V <sub>CE</sub> =5V, I <sub>C</sub> =1A    | 15      |     | 30  |        |
|                                      | h <sub>FE</sub> 2     | V <sub>CE</sub> =5V, I <sub>C</sub> =14A   | 4       |     | 7   |        |

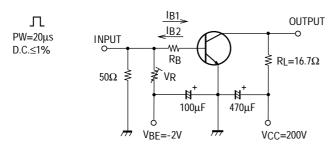
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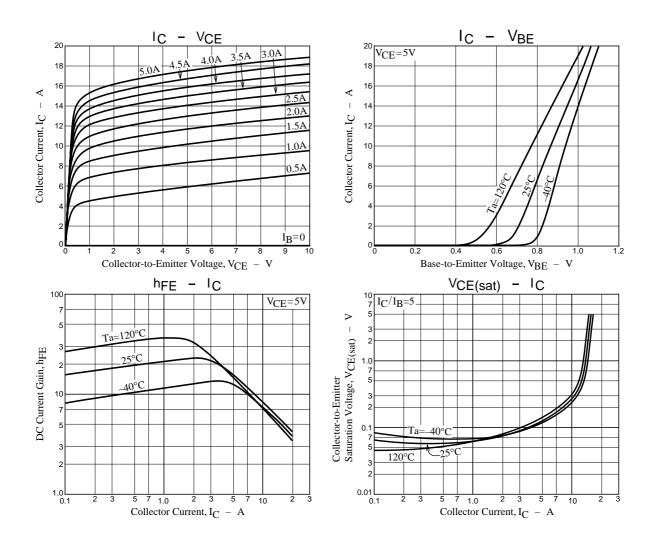
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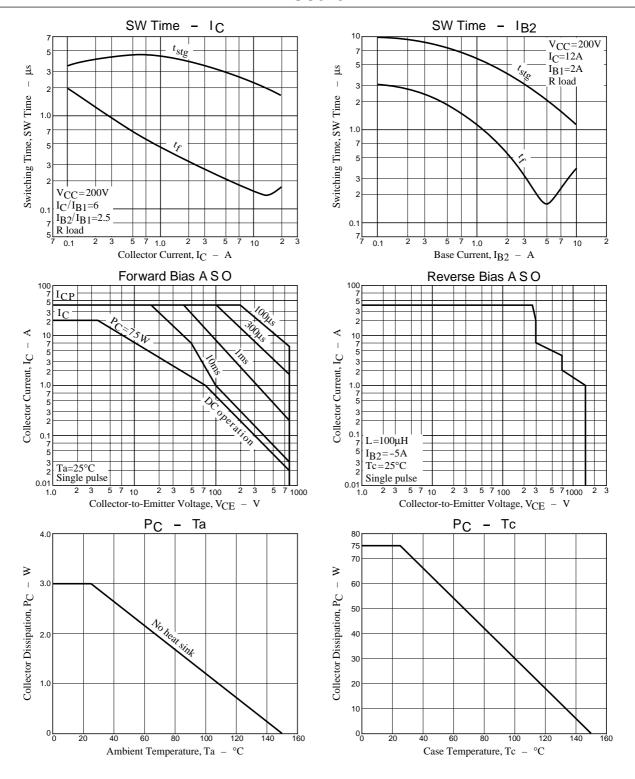
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| Parameter                               | Symbol               | Conditions   | Ratings |     |     | Unit  |
|---|----------------------|--|---------|-----|-----|-------|
|   |                      |  | min     | typ | max | Offic |
| Collector-to-Emitter Saturation Voltage | V <sub>CE(sat)</sub> | I <sub>C</sub> =14A, I <sub>B</sub> =3.5A                          |         |     | 5   | V     |
| Base-to-Emitter Saturation Voltage      | V <sub>BE(sat)</sub> | I <sub>C</sub> =14A, I <sub>B</sub> =3.5A                          |         |     | 1.5 | V     |
| Storage Time                            | t <sub>stg</sub>     | I <sub>C</sub> =12A, I <sub>B1</sub> =2.0A, I <sub>B2</sub> =-5.0A |         |     | 3.0 | μs    |
| Fall Time                               | t <sub>f</sub>       | I <sub>C</sub> =12A, I <sub>B1</sub> =2.0A, I <sub>B2</sub> =-5.0A |         |     | 0.2 | μs    |

## **Switching Time Test Circuit**







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